

SD103AWS / BWS / CWS

350mA Surface Mount Small Signal Schottky Diode-20V-40V

Features

- Low current rectification and high speed switching.
- Extremely small surface mount type.
- Low forward voltage drop.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts for green partner, exceeds environmental standards of MIL-STD-19500 /228
- Compliant to Halogen-free

Mechanical data

• Epoxy:UL94-V0 rated flame retardant

• Case: Molded plastic, SOD-323

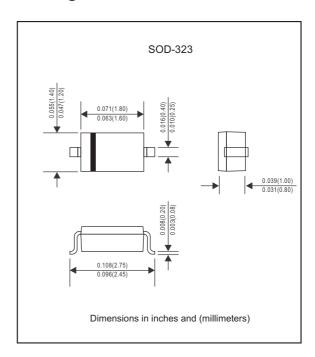
• Terminals : Solder plated, solderable per

MIL-STD-750, Method 2026

• Polarity: Indicated by cathode band

• Mounting Position : Any

Package outline



Maximum ratings (AT T_A=25°C unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	SD103AWS	SD103BWS	SD103CWS	UNIT
Peak repetitive reverse voltage Working peak reverse voltage DC blocking voltage		V _{RRM} V _{RWM} V _R	40	30	20	V
RMS reverse voltaget		$V_{R(RMS)}$	28	21	14	V
Average rectified output current		I _{F(AV)}		350		mA
Non-repetitive peak forward surge current	@ t < 1.0s	I _{FSM}		1.5		Α
Total device dissipation		P _D		200		mW
Thermal resistance	Junction to ambient	R _{eJA}		625		°C/W
Operating temperature		T,		-55 ~ +125		°C
Storage temperature		T _{STG}		-65 ~ +125		°C

Electrical Characteristics (AT T_A=25°C unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	I _R =100uA,SD103AWS I _R =100uA,SD103BWS I _R =100uA,SD103CWS	$V_{(BR)R}$	40 30 20			V
Forward voltage	I _F = 20mA I _F = 200mA	V _F			0.37 0.60	V
Reverse current	$V_R = 30 \text{ V, SD103AWS} $ $V_R = 20 \text{ V, SD103BWS} $ $V_R = 10 \text{ V, SD103CWS} $	I _R			5.0	uA
Typical Junction capacitance	V _R = 0 V, f = 1.0MHz	C _J		50		pF
Reverse recover time	$I_F = I_R = 200 \text{mA}, I_{rr} = 0.1 \text{ X } I_R,$ $R_L = 100_{OHM}$	XI _R ,		10		ns

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Rating and characteristic curves (SD103AWS / BWS / CWS)

Fig. 1 POWER DERATING CURVE

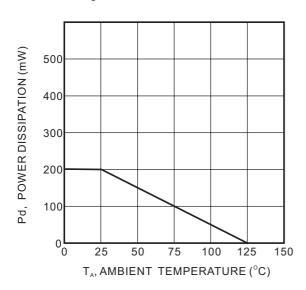


Fig. 2 TYPICAL FORWARD CHARACTERISTIC

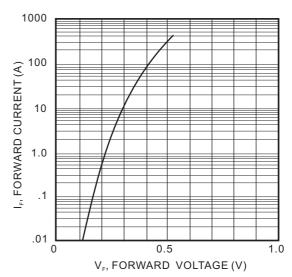
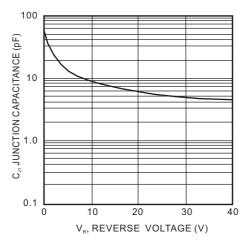


Fig. 3 TYPICAL JUNCTION CAPACITANCE VS REVERSE VOLTAGE



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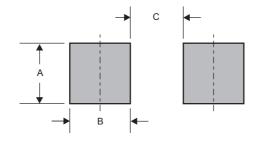
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode	1 🗆 🗆 2	12

Marking

Type number	Marking code	
SD103AWS	S4	
SD103BWS	S5	
SD103CWS	S6	

Suggested solder pad layout



Dimensions in inches and (millimeters)

PACKAGE	Α	В	С
SOD-323	0.033 (0.83)	0.025 (0.63)	0.063 (1.60)